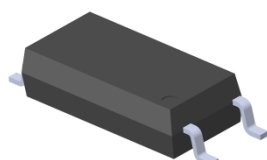
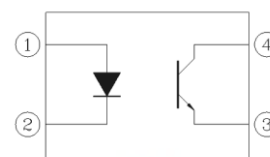


4 PIN LONG CREEPAGE SOP PHOTOTRANSISTOR PHOTOCOUPLER EL101X-G Series



Schematic



Pin Configuration

1. Anode
2. Cathode
3. Emitter
4. Collector

Features:

- Compliance Halogen Free
(Br < 900 ppm, Cl < 900 ppm, Br + Cl < 1500 ppm)
- Current transfer ratio
(CTR: 50~600% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)
(CTR: 63~320% at $I_F = 10\text{mA}$, $V_{CE} = 5\text{V}$)
- High isolation voltage between input and output (Viso = 5000 V rms)
- Compact 4 Pin SOP with a 2.1 mm profile
- Compliance with EU REACH
- 8mm long creepage distance
- The product itself will remain within RoHS compliant version
- UL and cUL approved (No. E214129)
- VDE approved (No. 40028391)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

The EL101X-G series devices consist of an infrared emitting diode, optically coupled to a phototransistor detector.

Compound use free halogens and Sb_2O_3 .

They are packaged in a 4-pin SOP package

Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	60	mA
	Peak forward current (1us, pulse)	I _{FP}	1.5	A
	Reverse voltage	V _R	6	V
	Power dissipation	P _D	100	mW
Output	Power dissipation	P _C	150	mW
	Collector current	I _C	50	mA
	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	7	V
	Total Power Dissipation	P _{TOT}	250	mW
	Isolation Voltage* ¹	V _{ISO}	5000	V _{rms}
	Operating Temperature	T _{OPR}	-55 to 110	°C
	Storage Temperature	T _{STG}	-55 to 125	°C
	Soldering Temperature* ²	T _{SOL}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

*2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage	V_F	-	1.45	1.5	V	$I_F = 50\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 6\text{V}$
Input capacitance	C_{in}	-	50	-	pF	$V = 0, f = 1\text{kHz}$

Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 0.1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Current Transfer ratio	EL1010	50	-	600	%	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$
	EL1017	80	-	160		
	EL1018	130	-	260		
	EL1019	200	-	400		
	EL1012	63	-	125	%	$I_F = 10\text{mA}, V_{CE} = 5\text{V}$
	EL1013	100	-	200		
	EL1014	160	-	320		
	EL1012	22	-	-		$I_F = 1\text{mA}, V_{CE} = 5\text{V}$
	EL1013	34	-	-		
	EL1014	56	-	-		
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	-	0.3	V	$I_F = 10\text{mA}, I_C = 1\text{mA}$
Isolation resistance	R_{IO}	5×10^{10}	-	-	Ω	$V_{IO} = 500\text{Vdc}, 40 \sim 60\% \text{ R.H.}$
Floating capacitance	C_{IO}	-	-	1.0	pF	$V_{IO} = 0, f = 1\text{MHz}$

Transfer Characteristics

Parameter	Symbol	Min	Typ. *	Max.	Unit	Condition
Turn on time	Ton	-	4	-	μs	$V_{CE} = 5V, I_C = 5mA,$ $R_L = 100\Omega$
Turn off time	Toff	-	3	-		
Rise time	t_r	-	-	18	μs	$V_{CE} = 5V, I_C = 5mA,$ $R_L = 100\Omega$
Fall time	t_f	-	-	18		

* Typical values at $T_a = 25^\circ\text{C}$

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Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs Forward Voltage

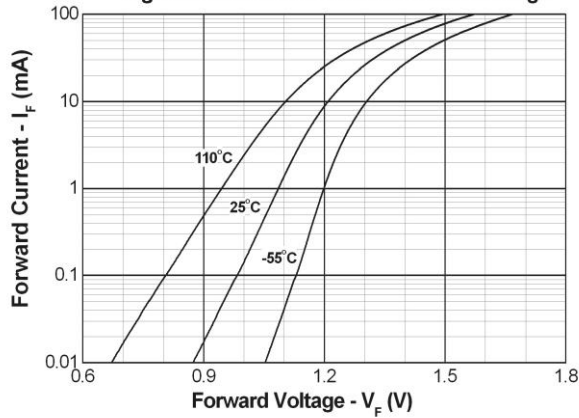


Figure 2. Dark Current vs Ambient Temperature

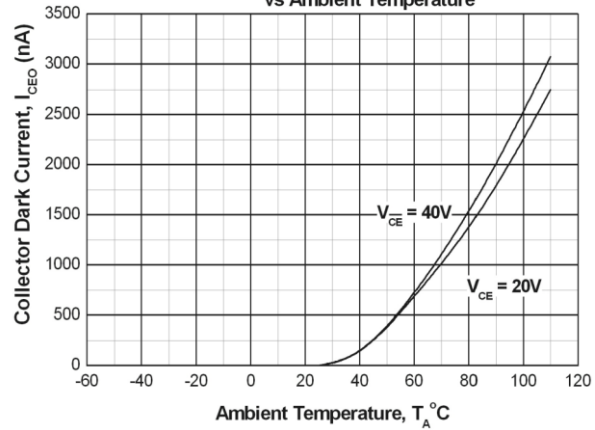


Figure 3. Collector Current vs. Collector Emitter Voltage

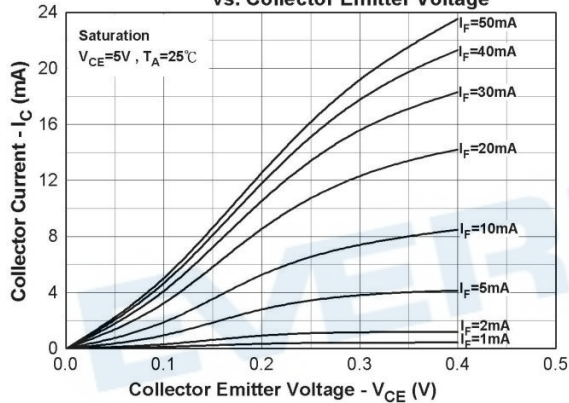


Figure 4. Collector Current vs. Collector Emitter Voltage

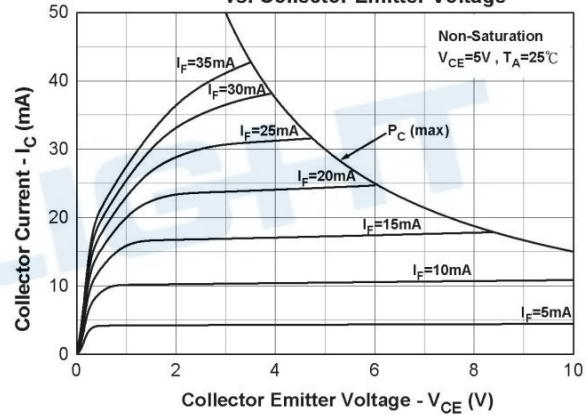


Figure 5. Normalized Collector Current vs. Forward Current

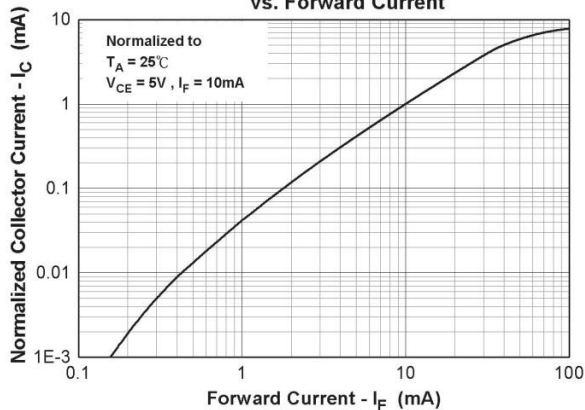


Figure 6. Normalized Current Transfer Ratio vs. Forward Current

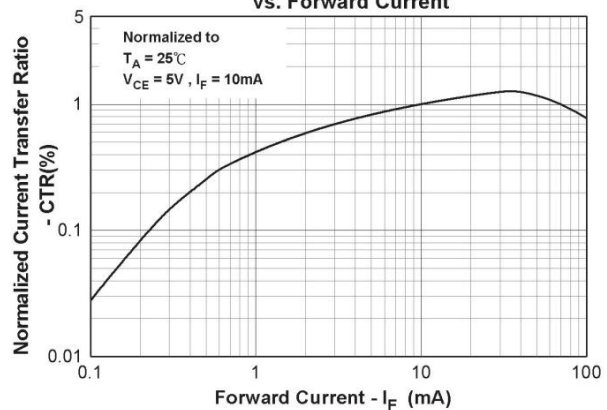


Figure 7. Normalized Current Transfer Ratio vs. Ambient Temperature

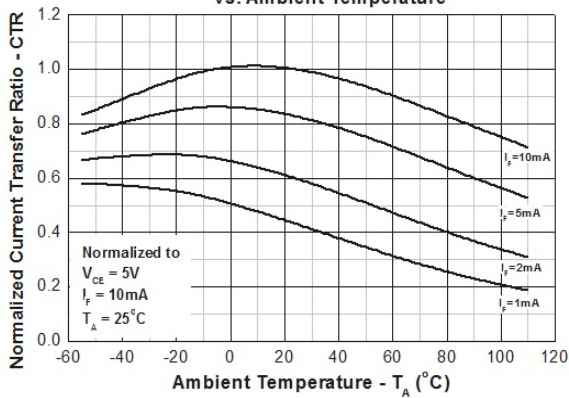


Figure 8. Normalized Current Transfer Ratio vs. Ambient Temperature

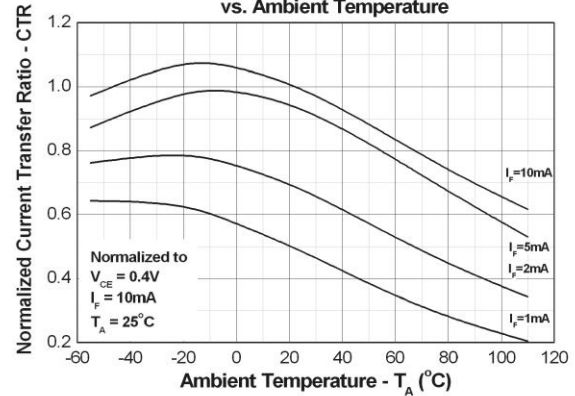


Figure 9. Turn on/off Time vs. Collector Current

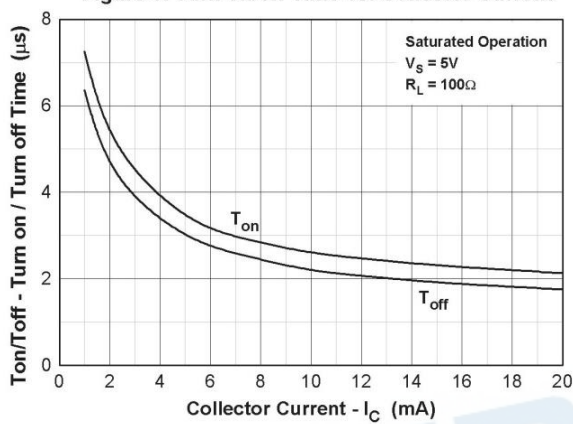


Figure 10. Turn on/off Time vs. Forward Current

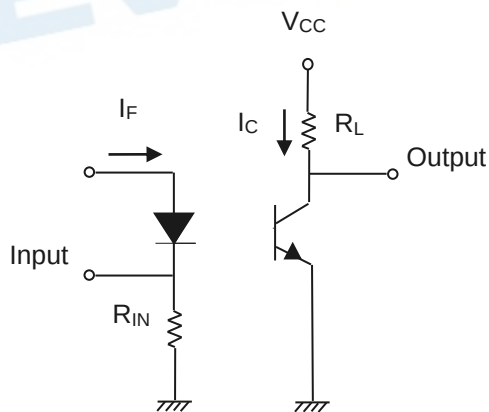
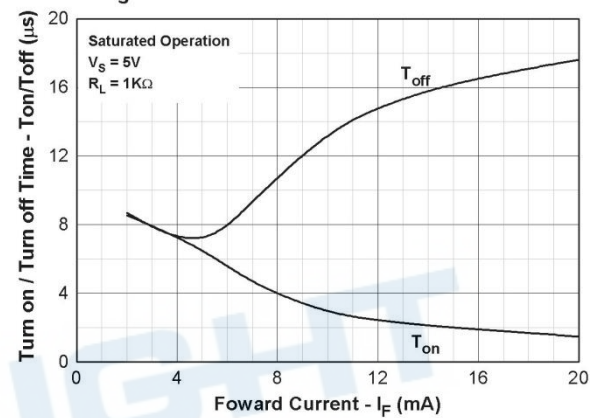


Figure 11. Switching Time Test Circuit & Waveforms

Order Information

Part Number

EL101X(Y)-VG

Notes

EL101 = Part No.

X = CTR Rank (0, 2, 3, 4, 7, 8 or 9)

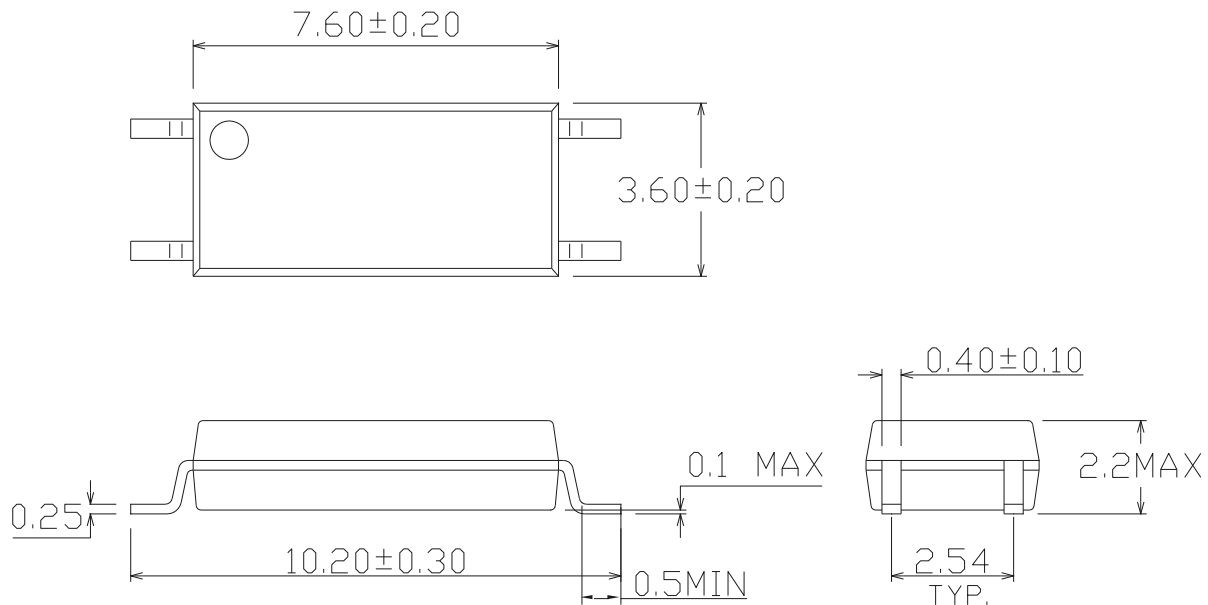
Y = Tape and reel option (TA, TB or none)

V = VDE safety (optional)

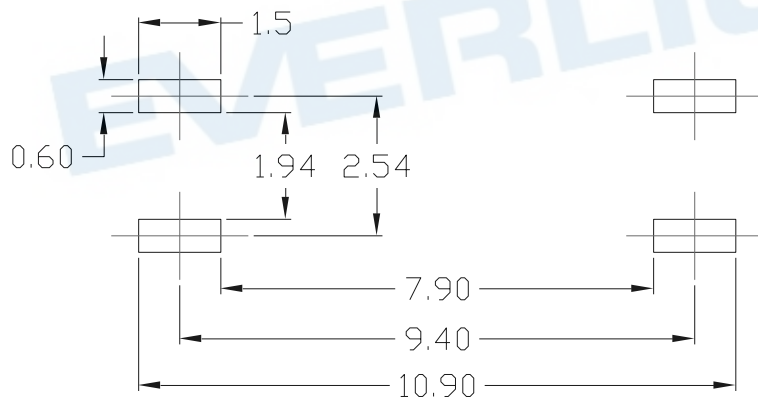
G = Halogens free

Option	Description	Packing quantity
None	Standard SMD option	100 units per tube
-V	Standard SMD option + VDE	100 units per tube
(TA)	TA Tape & reel option	3000 units per reel
(TB)	TB Tape & reel option	3000 units per reel
(TA)-V	TA Tape & reel option + VDE	3000 units per reel
(TB)-V	TB Tape & reel option + VDE	3000 units per reel

Package Dimension (Dimensions in mm)



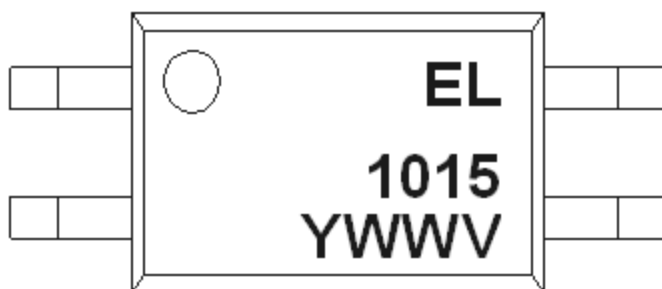
Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only.
Please modify the pad dimension based on individual need.

Device Marking

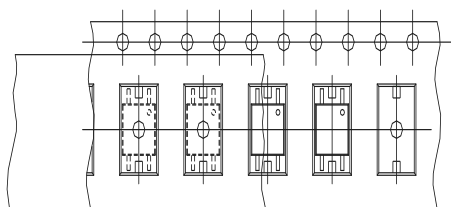


Notes

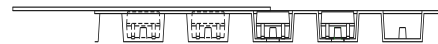
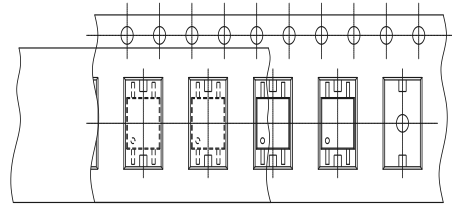
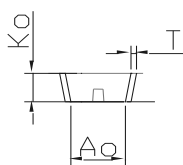
EL	denotes Everlight
1015	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

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Option TA



Option TB

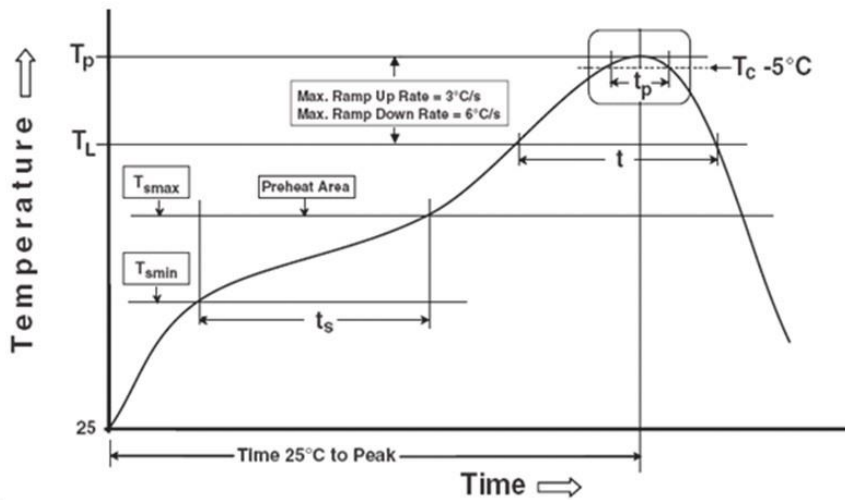
[illegible]

10

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Notes

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})	150 °C
Temperature max (T_{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_P)	3 °C/second max

Other

Liquidus Temperature (T_L)	217 °C
Time above Liquidus Temperature (t_L)	60-100 sec
Peak Temperature (T_P)	260°C
Time within 5 °C of Actual Peak Temperature: $T_P - 5^\circ\text{C}$	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.
Reflow times	3 times

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2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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